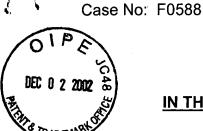
le Response E M. Baurson 12/12/02

PATENT



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Qi Xiang

Serial No.: 09/902,429

Serial No.: 09/902,429

Filing Date: July 10, 2001

SILICON ON INSULATOR FIELD EFFECT TRANSISTOR WITH

HETEROJUNCTION GATE.

Examiner: Laura M. Schillinger

Art Unit: 2813 **AFTER FINAL REPLY**

EXPEDITED HANDLING REQUESTED

Box AF Assistant Commissioner for Patents Washington, D.C. 20231

RESPONSE TO OFFICE ACTION DATED SEPTEMBER 25, 2002

Examiner:

The applicants respectfully request favorable reconsideration of the application in view of the following comments.

REMARKS

Claims 1-14 and 21-27 are presently under consideration. Favorable reconsideration of the application is respectfully requested.